

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

Title of Invention

PROCESS OPTIONS OF FORMING SILICIDED METAL GATES
FOR ADVANCED CMOS DEVICES

Application Number :

Confirmation Number:

First Named Applicant: Ricky Amos

Attorney Docket Number: FIS920020157US1

Art Unit:

Examiner:

Search string: (5723893 or 6147388 or 6180501 or 6277719 or 6465312).pn

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

int	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
AC	1	5723893	1998-03-03	YU, ET AL.			
	2	6147388	2000-11-14	MA, ET AL.			
	3	6180501	2001-01-30	PEY, ET AL.			
	4	6277719	2001-08-21	CHERN, ET AL.			
AC	5	6465312	2002-10-15	YU			

Signature

Examiner Name	Date
<i>Chae J. fa</i>	<i>8/15/05</i>